CMOD6001

ULTRAmini™
SURFACE MOUNT LOW LEAKAGE
SWITCHING DIODE

SOD-523 CASE

ULTRAmini™

SOD-523 CASE

Central™
Semiconductor Corp.

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMOD6001 type is a silicon switching diode manufactured by the epitaxial planar process, epoxy molded in a ULTRAmini™ surface mount package, designed for switching applications requiring a extremely low leakage diode.
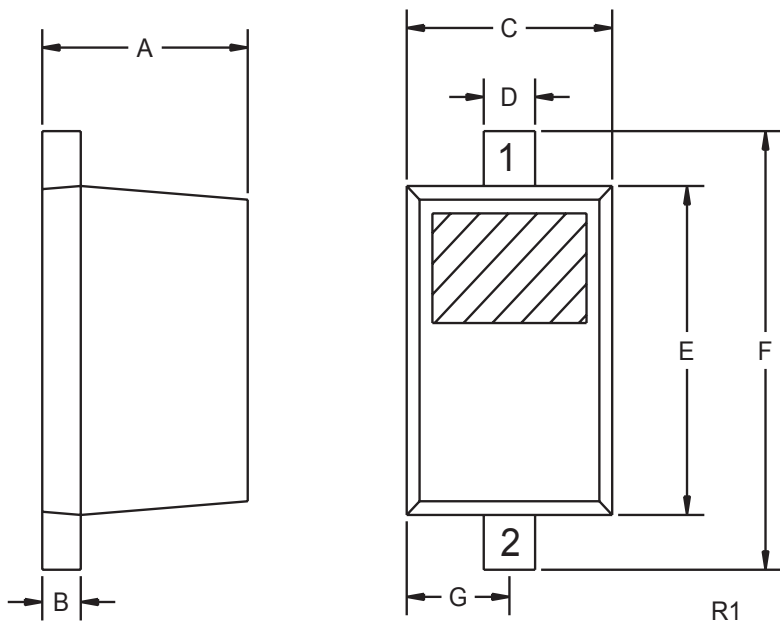
The marking code is 61.

MAXIMUM RATINGS: (T_A=25°C)

	SYMBOL		UNITS
Continuous Reverse Voltage	V_R	75	V
Peak Repetitive Reverse Voltage	V_{RRM}	100	V
Continuous Forward Current	I_F	250	mA
Peak Repetitive Forward Current	I_{FRM}	250	mA
Forward Surge Current, tp=1.0 μsec.	I_{FSM}	4000	mA
Forward Surge Current, tp=1.0 sec.	I_{FSM}	1000	mA
Power Dissipation	P_D	250	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	°C
Thermal Resistance	Θ_{JA}	500	°C/W

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_R	V_R=75V		500	pA
V_{BR}	I_R=100μA	100		V
V_F	I_F=1.0mA		0.85	V
V_F	I_F=10mA		0.95	V
V_F	I_F=100mA		1.1	V
C_T	V_R=0, f=1.0MHz		2.0	pF
t_{rr}	I_R=I_F=10mA, R_L=100Ω, Rec. to 1.0mA		3.0	μs

R1 (18-June 2001)

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SOD-523 - MECHANICAL OUTLINE

R1

LEAD CODE:

1) Cathode
2) Anode

MARKING CODE: 61

DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
A	0.020	0.031	0.50	0.80
B	0.004	0.008	0.10	0.20
C	0.028	0.035	0.70	0.90
D	0.008	0.011	0.20	0.28
E	0.039	0.055	1.00	1.40
F	0.055	0.071	1.40	1.80
G	0.016		0.40	

SOD-523 (REV: R1)

R1 (18-June 2001)